

SMALL SIGNAL NPN TRANSISTOR

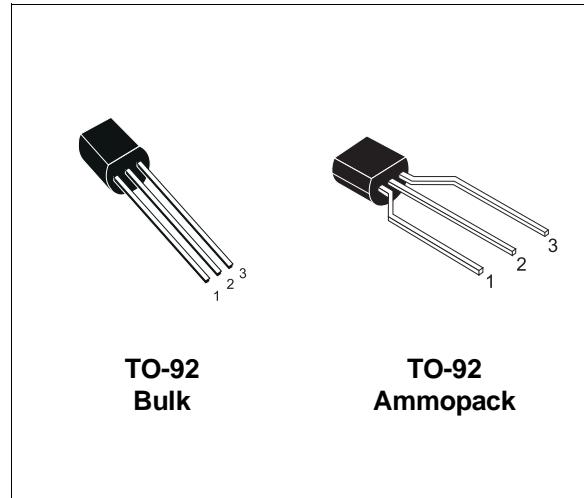
PRELIMINARY DATA

Ordering Code	Marking	Package / Shipment
BC635	BC635	TO-92 / Bulk
BC635-AP	BC635	TO-92 / Ammopack

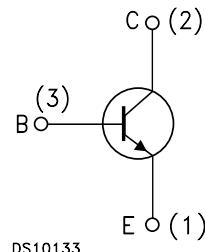
- SILICON EPITAXIAL PLANAR NPN TRANSISTOR
- TO-92 PACKAGE SUITABLE FOR THROUGH-HOLE PCB ASSEMBLY
- THE PNP COMPLEMENTARY TYPE IS BC636

APPLICATIONS

- WELL SUITABLE FOR TV AND HOME APPLIANCE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTORS WITH HIGH GAIN AND LOW SATURATION VOLTAGE



INTERNAL SCHEMATIC DIAGRAM



DS10133

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CER}	Collector-Emitter Voltage ($R_{BE} = 1\text{K}\Omega$)	45	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	45	V
V_{CES}	Collector-Emitter Voltage ($V_{BE} = 0$)	45	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	5	V
I_C	Collector Current	1	A
I_{CM}	Collector Peak Current	1.5	A
P_{tot}	Total Dissipation at $T_{amb} = 25^\circ\text{C}$	1	W
T_{stg}	Storage Temperature	-65 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C

BC635

THERMAL DATA

$R_{\text{thj-amb}}$ •	Thermal Resistance Junction-Ambient	Max	125	$^{\circ}\text{C}/\text{W}$
$R_{\text{thj-Case}}$ •	Thermal Resistance Junction-Case	Max	83.3	$^{\circ}\text{C}/\text{W}$

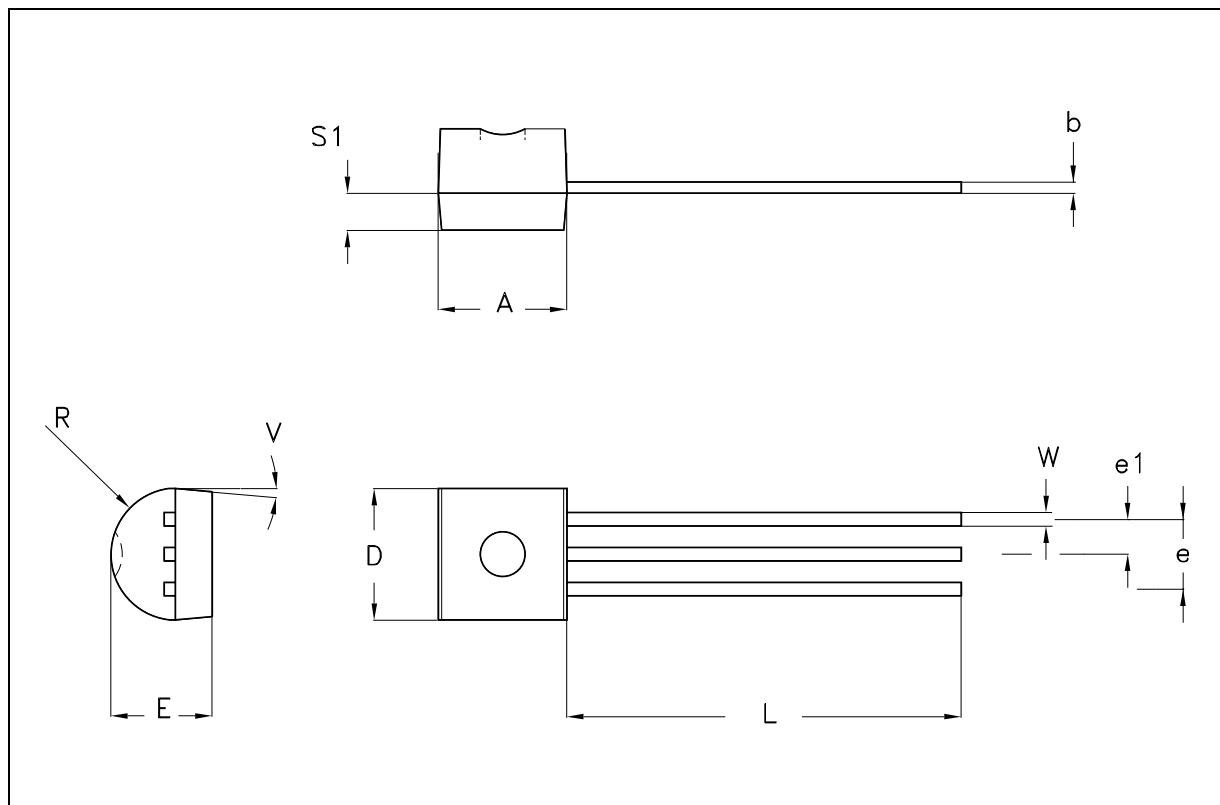
ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current ($I_E = 0$)	$V_{\text{CB}} = 30 \text{ V}$			0.1	μA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{\text{EB}} = 5 \text{ V}$			0.1	μA
$V_{(\text{BR})\text{CEO}}^*$	Collector-Emitter Breakdown Voltage ($I_B = 0$)	$I_C = 10 \text{ mA}$	45			V
$V_{\text{CE}(\text{sat})}^*$	Collector-Emitter Saturation Voltage	$I_C = 500 \text{ mA}$ $I_B = 50 \text{ mA}$			0.5	V
$V_{\text{BE}(\text{on})}^*$	Base-Emitter On Voltage	$I_C = 500 \text{ mA}$ $V_{\text{CE}} = 2 \text{ V}$			1	V
h_{FE}	DC Current Gain	$I_C = 5 \text{ mA}$ $V_{\text{CE}} = 2 \text{ V}$ $I_C = 150 \text{ mA}$ $V_{\text{CE}} = 2 \text{ V}$ $I_C = 500 \text{ mA}$ $V_{\text{CE}} = 2 \text{ V}$	25 40 25		250	
f_T	Transition Frequency	$I_C = 10 \text{ mA}$ $V_{\text{CE}} = 5 \text{ V}$ $f = 50\text{MHz}$		100		MHz

* Pulsed: Pulse duration = 300 μs , duty cycle $\leq 2\%$

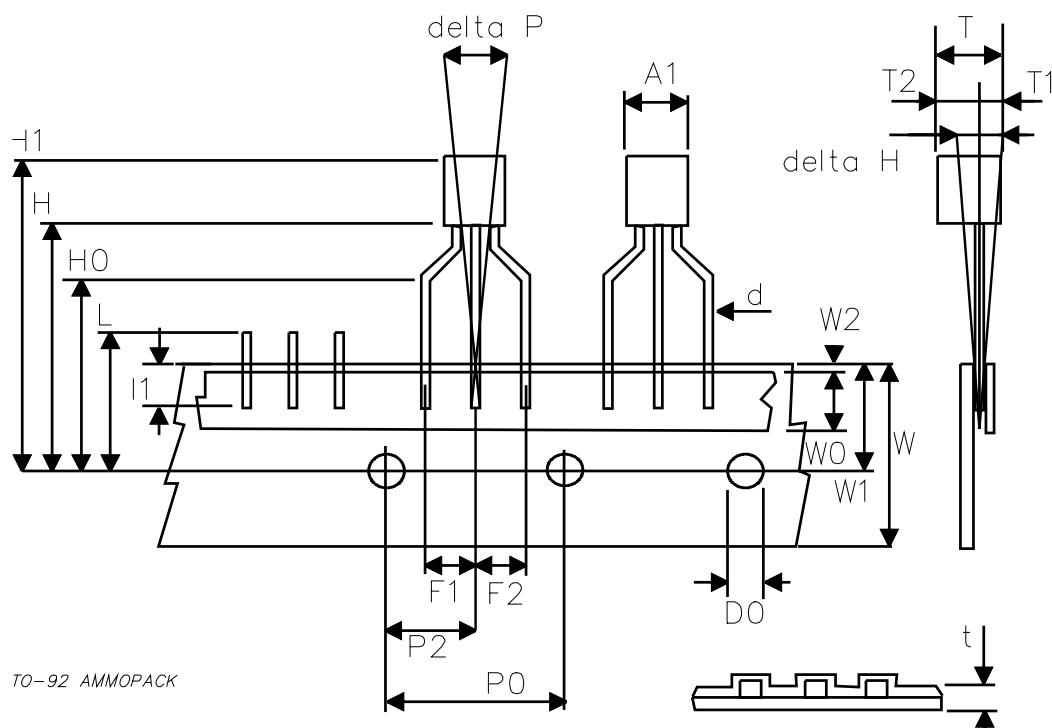
TO-92 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.32		4.95	0.170		0.195
b	0.36		0.51	0.014		0.020
D	4.45		4.95	0.175		0.194
E	3.30		3.94	0.130		0.155
e	2.41		2.67	0.095		0.105
e1	1.14		1.40	0.045		0.055
L	12.70		15.49	0.500		0.609
R	2.16		2.41	0.085		0.094
S1	1.14		1.52	0.045		0.059
W	0.41		0.56	0.016		0.022
V	4 degree		6 degree	4 degree		6 degree



TO-92 AMMOPACK SHIPMENT (Suffix "-AP") MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A1			4.80			0.189
T			3.80			0.150
T1			1.60			0.063
T2			2.30			0.091
d			0.48			0.019
P0	12.50	12.70	12.90	0.492	0.500	0.508
P2	5.65	6.35	7.05	0.222	0.250	0.278
F1,F2	2.44	2.54	2.94	0.096	0.100	0.116
delta H	-2.00		2.00	-0.079		0.079
W	17.50	18.00	19.00	0.689	0.709	0.748
W0	5.70	6.00	6.30	0.224	0.236	0.248
W1	8.50	9.00	9.25	0.335	0.354	0.364
W2			0.50			0.020
H	18.50		20.50	0.728		0.807
H0	15.50	16.00	16.50	0.610	0.630	0.650
H1			25.00			0.984
D0	3.80	4.00	4.20	0.150	0.157	0.165
t			0.90			0.035
L			11.00			0.433
I1	3.00			0.118		
delta P	-1.00		1.00	-0.039		0.039



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